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# HD74AC194

4-bit Bidirectional Unviersal Shift Register

REJ03D0259–0200Z (Previous ADE-205-379 (Z)) Rev.2.00 Jul.16.2004

### Description

This bidirectional shift register is designed to incorporate virtually all of the features a system designer may want in a shift register. It features parallel inputs, parallel outputs, right shift and left shift serial inputs, operating mode control inputs, and a direct overriding clear line. The register has four destinct modes of operation: parallel (broadside) load, shift right (in the direction  $Q_0$  toward  $Q_3$ ); shift left; inhibit clock (do nothing).

Synchronous parallel loading is accomplished by applying the four bits of data and taking both mode control inputs,  $S_0$  and  $S_1$ , high. The data are loaded into their respective flip-flops and appear at the output after the positive transition of the clock input. During loading, serial data flow is inhibited. Shift right is accomplished synchronously with the rising edge of the clock pulse when  $S_0$  is high and  $S_1$  is low. Serial date for this mode is entered at the shift right data input. When  $S_0$  is low and  $S_1$  is high, data shifts left synchronously and new data is entered at the shifts left serial input. Clocking of the flip-flops is inhibited when both mode control inputs are low. The mode control inputs should be changed only when the clock input is high.

#### Features

- Asynchronous Master Reset
- Hole (Do Nothing) Mode
- Outputs Source/Sink 24 mA
- Ordering Information

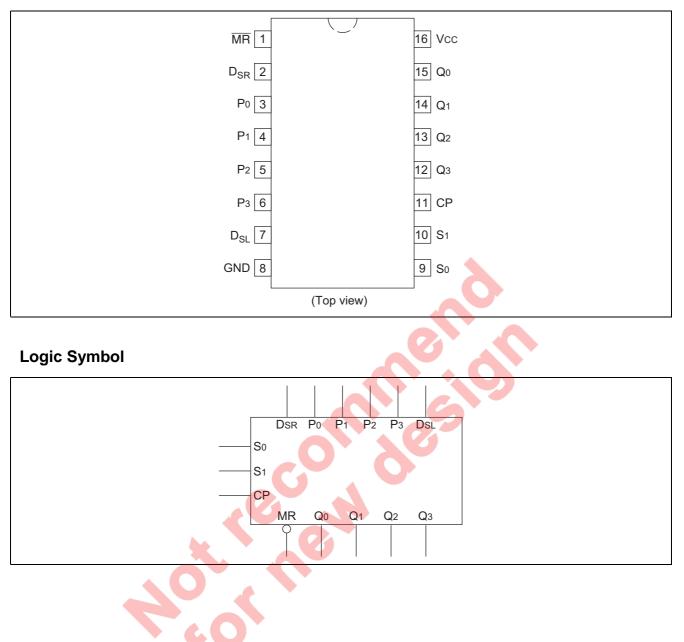
Part Name	Package Type	Package Code	Package Abbreviation	Taping Abbreviation (Quantity)
HD74AC194FPEL	SOP-16 pin (JEITA)	FP-16DAV	FP	EL (2,000 pcs/reel)
HD74AC194RPEL	SOP-16 pin (JEDEC)	FP-16DNV	RP	EL (2,500 pcs/reel)

Notes: 1. Please consult the sales office for the above package availability.

2. The packages with lead-free pins are distinguished from the conventional products by adding V at the end of the package code.



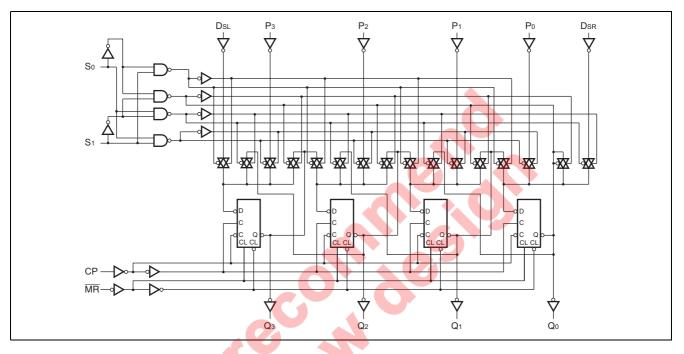
# **Pin Arrangement**



Pin Names	i
$\mathbf{S}_0, \mathbf{S}_1$	Mode Control Inputs
$P_0$ to $P_3$	Parallel Data Inputs
$D_{SR}$	Serial Data Input (Shift Right)
$D_{SL}$	Serial Data Input (Shift Left)
CP	Clock Pulse Input (Active Rising Edge)
MR	Asynchronous Master Reset Input (Active LOW)

 $Q_0$  to  $Q_3$  Parallel Outputs

## Logic Diagram



### Mode Select Table

		Inputs						Output			
Operating Mode	MR	S <sub>1</sub>	S₀	D <sub>SR</sub>	D <sub>SL</sub>	Pn	Q <sub>0</sub>	<b>Q</b> <sub>1</sub>	<b>Q</b> <sub>2</sub>	$Q_3$	
Reset		Х	Х	Х	Х	Х	L	L	L	L	
Hold	н	L	L	Х	Х	Х	$q_0$	q <sub>1</sub>	q <sub>2</sub>	q <sub>3</sub>	
Shift Left	н 🔰	Н	L	Х	L	Х	q <sub>1</sub>	<b>q</b> <sub>2</sub>	q <sub>3</sub>	L	
	Н	Н	L	Х	Н	Х	q <sub>1</sub>	<b>q</b> <sub>2</sub>	q <sub>3</sub>	Н	
Shift Right	Н	L	Н	L	Х	Х	L	<b>q</b> <sub>0</sub>	q <sub>1</sub>	<b>q</b> <sub>2</sub>	
	Н	L	Н	Н	Х	Х	Н	q <sub>0</sub>	q <sub>1</sub>	<b>q</b> <sub>2</sub>	
Parallel Load	Н	Н	Н	Х	Х	p <sub>n</sub>	p <sub>0</sub>	р <sub>1</sub>	p <sub>2</sub>	p <sub>3</sub>	

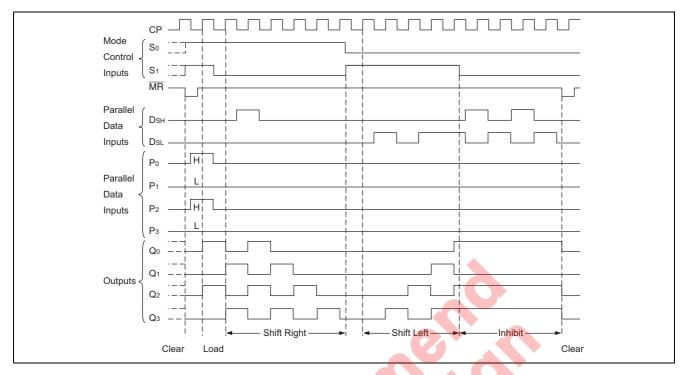
H : HIGH Voltage Level

L : LOW Voltage Level

 $p_n(q_n)$ : Lower case letters indicate the state of the referenced input (or output) one setup time prior to the LOW-to-HIGH clock transition

X : Immaterial

# **Timing Diagram**



# **Absolute Maximum Ratings**

Item	Symbol	Ratings	Unit	Condition
Supply voltage	V <sub>cc</sub>	-0.5 to 7	V	
DC input diode current	I <sub>IK</sub>	-20	mA	$V_1 = -0.5V$
		20	mA	$V_1 = Vcc+0.5V$
DC input voltage	V	-0.5 to Vcc+0.5	V	
DC output diode current	Ι <sub>οκ</sub>	-50	mA	$V_{\rm O} = -0.5V$
		50	mA	$V_0 = Vcc+0.5V$
DC output voltage	Vo	-0.5 to Vcc+0.5	V	
DC output source or sink current	I <sub>o</sub>	±50	mA	
DC V <sub>cc</sub> or ground current per output pin	I <sub>CC</sub> , I <sub>GND</sub>	±50	mA	
Storage temperature	Tstg	-65 to +150	°C	

# **Recommended Operating Conditions**

Item	Symbol	Ratings	Unit	Condition
Supply voltage	V <sub>cc</sub>	2 to 6	V	
Input and output voltage	V <sub>I</sub> , V <sub>O</sub>	0 to V <sub>cc</sub>	V	
Operating temperature	Та	-40 to +85	°C	
Input rise and fall time	tr, tf	8	ns/V	$V_{cc} = 3.0V$
(except Schmitt inputs)				V <sub>cc</sub> = 4.5 V
$V_{IN}$ 30% to 70% $V_{CC}$				V <sub>CC</sub> = 5.5 V

#### **DC Characteristics**

ltem	Sym- bol	Vcc (V)	1	Га = 25°(	C	Ta = -40 to +85°C										Unit	Condition
			min.	typ.	max.	min.	max.										
Input Voltage	V <sub>IH</sub>	3.0	2.1	1.5	—	2.1	—	V	$V_{OUT} = 0.1 \text{ V or } V_{CC} - 0.1 \text{ V}$								
		4.5	3.15	2.25	—	3.15	—										
		5.5	3.85	2.75	_	3.85	—										
	V <sub>IL</sub>	3.0	—	1.50	0.9	—	0.9		$V_{OUT} = 0.1 \text{ V or } V_{CC} - 0.1 \text{ V}$								
		4.5	—	2.25	1.35	—	1.35										
		5.5	—	2.75	1.65	—	1.65										
Output voltage	V <sub>OH</sub>	3.0	2.9	2.99	—	2.9	—	V	$V_{IN} = V_{IL} \text{ or } V_{IH}$								
		4.5	4.4	4.49	—	4.4	—		I <sub>OUT</sub> = -50 μA								
		5.5	5.4	5.49	—	5.4	—										
		3.0	2.58	—	—	2.48	—		$V_{IN} = V_{IL} \text{ or } V_{IH}$ $I_{OH} = -12 \text{ m/}$								
		4.5	3.94	—	—	3.80	—		$I_{OH} = -24 \text{ m/}$								
		5.5	4.94	—	—	4.80	—		I <sub>OH</sub> = -24 m/								
	V <sub>OL</sub>	3.0	—	0.002	0.1	—	0.1		$V_{IN} = V_{IL} \text{ or } V_{IH}$								
		4.5	—	0.001	0.1	—	0.1		I <sub>ουτ</sub> = 50 μA								
		5.5	—	0.001	0.1	—	0.1										
		3.0	—	—	0.32	—	0.37		$V_{IN} = V_{IL} \text{ or } V_{IH}$ $I_{OL} = 12 \text{ mA}$								
		4.5	—	—	0.32	-	0.37		I <sub>OL</sub> = 24 mA								
		5.5	—	—	0.32	-	0.37		I <sub>OL</sub> = 24 mA								
Input leakage current	I <sub>IN</sub>	5.5	—	—	±0.1		±1.0	μA	$V_{IN} = V_{CC}$ or GND								
Dynamic output	I <sub>OLD</sub>	5.5	—	—		86		mA	V <sub>OLD</sub> = 1.1 V								
current*	I <sub>OHD</sub>	5.5	—	—		-75		mA	V <sub>OHD</sub> = 3.85 V								
Quiescent supply current	I <sub>cc</sub>	5.5	—	65	8.0	-0	80	μA	$V_{IN} = V_{CC}$ or ground								

\*Maximum test duration 2.0 ms, one output loaded at a time.

# **AC Characteristics**

	0		Ta = +25°C C <sub>L</sub> = 50 pF			C to +85°C 50 pF		
Item	Symbol	V <sub>cc</sub> (V)* <sup>1</sup>	Min	Тур	Max	Min	Max	Unit
Maximum clock	f <sub>max</sub>	3.3	75	—		65		MHz
frequency		5.0	100	—		85		
Propagation delay	t <sub>PLH</sub>	3.3	1.0	—	13.0	1.0	15.0	ns
CP to Q <sub>n</sub>		5.0	1.0	—	10.0	1.0	11.5	
Propagation delay	t <sub>PHL</sub>	3.3	1.0	—	13.0	1.0	15.0	ns
CP to Q <sub>n</sub>		5.0	1.0	—	10.0	1.0	11.5	
Propagation delay	t <sub>PHL</sub>	3.3	1.0	_	10.5	1.0	12.5	ns
$\overline{MR}$ to $Q_{n}$		5.0	1.0		8.0	1.0	9.0	

 Note:
 1.
 Voltage Range 3.3 is 3.3 V ± 0.3 V

 Voltage Range 5.0 is 5.0 V ± 0.5 V

### **AC Operating Requirements**

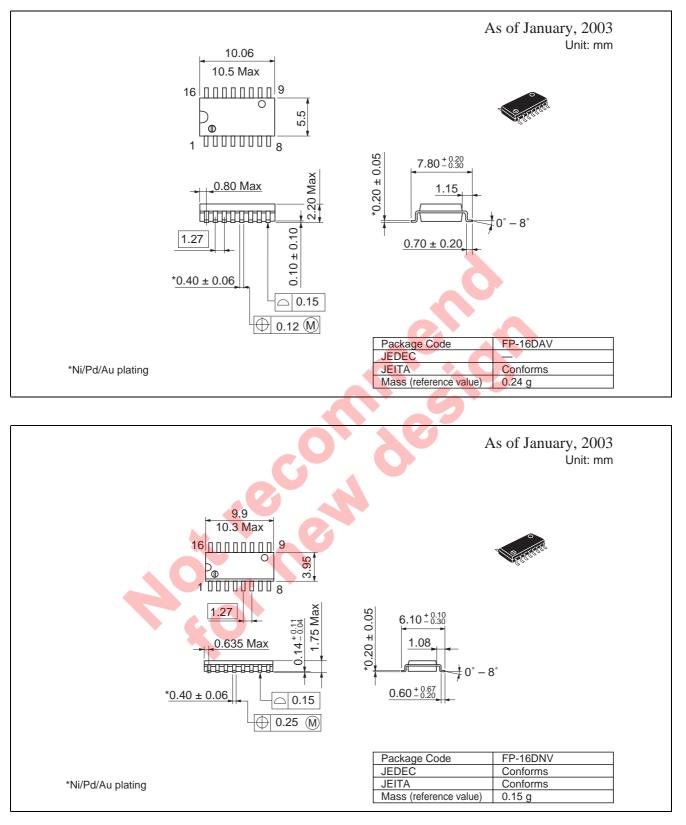
			Ta = +25°C C <sub>L</sub> = 50 pF		Ta = -40°C to +85°C C <sub>L</sub> = 50 pF	
Item	Symbol	V <sub>cc</sub> (V)* <sup>1</sup>	Тур	Guarantee	d Minimum	Unit
Setup time, HIGH or LOW	t <sub>su</sub>	3.3	—	5.5	7.0	ns
Pn or D <sub>SR</sub> or D <sub>SL</sub> to CP		5.0	—	4.0	5.0	
Hold time, HIGH or LOW	t <sub>h</sub>	3.3	—	2.0	3.0	ns
Pn or D <sub>SR</sub> or D <sub>SL</sub> to CP		5.0	—	1.5	2.0	
Setup time, HIGH or LOW	t <sub>su</sub>	3.3	—	6.0	7.5	ns
S <sub>n</sub> to CP		5.0	—	4.5	5.5	
Hold time, HIGH or LOW	t <sub>h</sub>	3.3	—	0.0	0.0	ns
S <sub>n</sub> to CP		5.0	—	0.0	0.0	
Recovery time	t <sub>rec</sub>	3.3	—	0.5	0.5	ns
MR to CP		5.0	—	0.5	0.5	]
Pulse width	t <sub>w</sub>	3.3	—	5.5	7.0	ns
		5.0	_	4.5	5.0	]

Note: 1. Voltage Range 3.3 is 3.3 V ± 0.3 V Voltage Range 5.0 is 5.0 V ± 0.5 V

### Capacitance

Item	Symbol	Тур 🧹	Unit		Condition
Input capacitance	C <sub>IN</sub>	4.5	pF	$V_{cc} = 5.5 V$	
Power dissipation capacitance	C <sub>PD</sub>	100	pF	V <sub>cc</sub> = 5.0 V	
			96		

### **Package Dimensions**



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